

60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C (Note 9)
001/	2.8mΩ @ V <sub>GS</sub> = 10V	100A
60V	4.4mΩ @ V <sub>GS</sub> = 4.5V	100A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Pin1

Bottom View

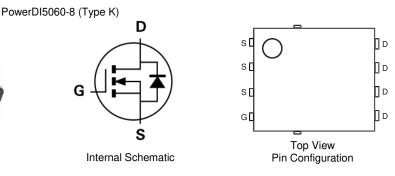
- Switching
- Synchronous Rectification
- DC-DC Converters

#### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.097 grams (Approximate)



## Ordering Information (Note 4)

Top View

Part Number	Case	Packaging
DMTH62M8LPS-13	PowerDI5060-8 (Type K)	2,500 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



DIII = Manufacturer's Marking TH62M8LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)

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# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Notes 6 & 9)	$T_{\rm C}$ = +25°C	ID	100	А
Continuous Drain Current, VGS - TOV (Notes 0 & 3)	$T_{C} = +100^{\circ}C$		100	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	400	А
Continuous Body Diode Forward Current (Note 6)	$T_{C} = +25^{\circ}C$	IS	100	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I <sub>SM</sub>	400	А	
Avalanche Current, L = 0.2mH	I <sub>AS</sub>	44	А	
Avalanche Energy, L = 0.2mH	Eas	193	mJ	

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	3.13	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	48	°C/W
Total Power Dissipation (Note 6)	PD	115	W
Thermal Resistance, Junction to Case (Note 6)	R <sub>eJC</sub>	1.3	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)					•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						·	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	1.62	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance		—	2.10	2.8	mΩ	$V_{GS} = 10V, I_D = 50A$	
	R <sub>DS(ON)</sub>	_	2.95	4.4	11152	$V_{GS} = 4.5V, I_D = 50A$	
Diode Forward Voltage	V <sub>SD</sub>	—	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	4515	—		$\label{eq:VDS} \begin{split} V_{DS} &= 30V, \ V_{GS} = 0V, \\ f &= 1 MHz \end{split}$	
Output Capacitance	Coss	_	1477	—	pF		
Reverse Transfer Capacitance	Crss	_	135.3	_			
Gate Resistance	R <sub>G</sub>	_	0.64	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	96.3	—		V <sub>DD</sub> = 30V, I <sub>D</sub> = 25A	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	47.4	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	—	14.1	—	10		
Gate-Drain Charge	Q <sub>gd</sub>	—	21.4	—			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.9	—		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 25A, R_{G} = 3.5\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	17.7	—			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	53.5	—	ns		
Turn-Off Fall Time	tF	_	32.9	—	]		
Reverse Recovery Time	t <sub>RR</sub>	—	49.7	—	ns		
Reverse Recovery Charge	Q <sub>RR</sub>	_	78.9	—	nC	−I <sub>F</sub> = 25A, di/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

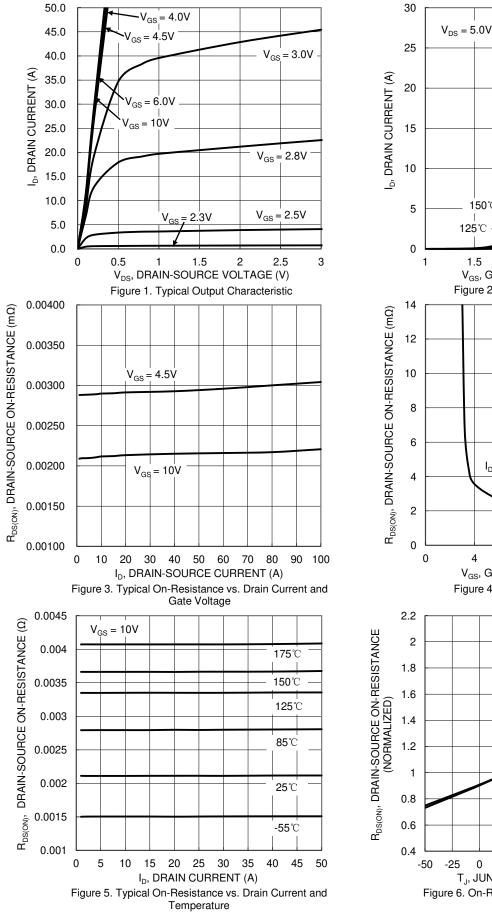
7. Short duration pulse test used to minimize self-heating effect.

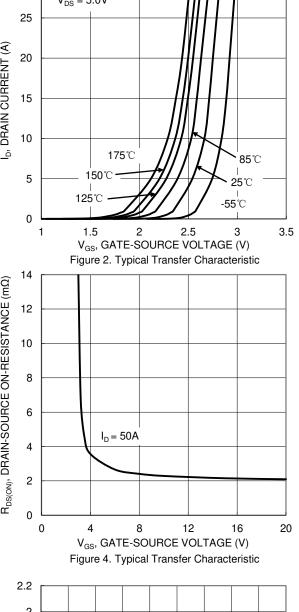
8. Guaranteed by design. Not subject to product testing.

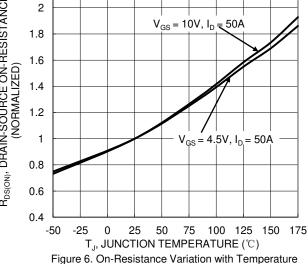
9. Limited by package.



## DMTH62M8LPS



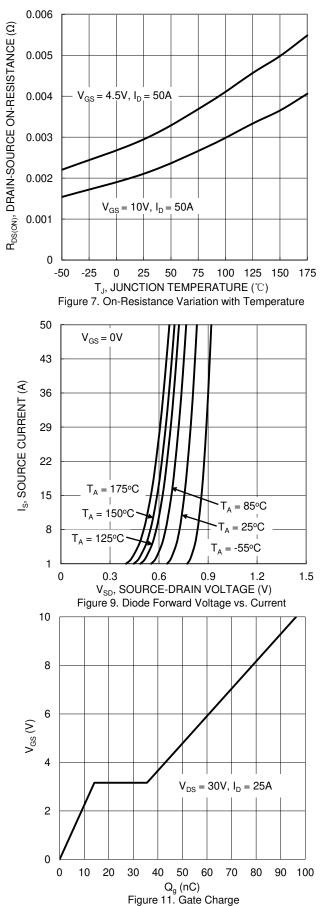


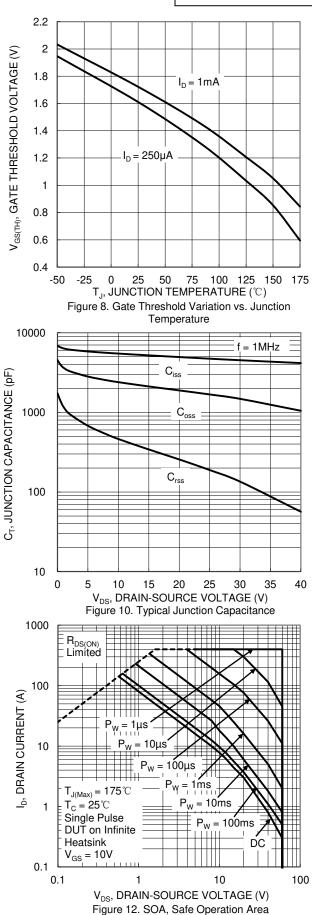


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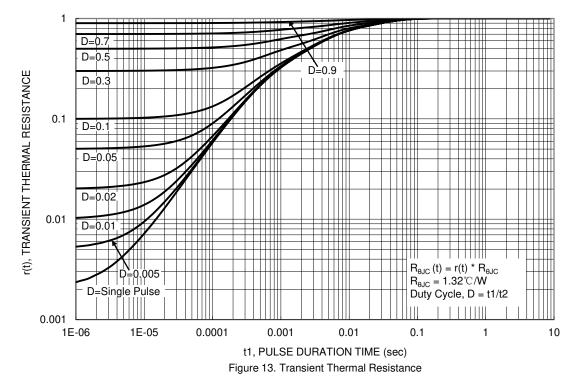
## DMTH62M8LPS





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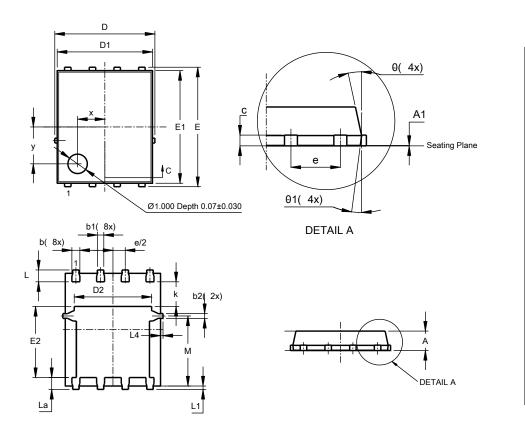




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (Type K)

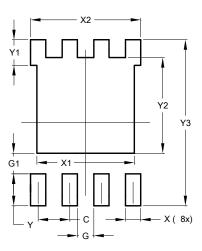


PowerDI5060-8 (Type K)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
С	0.23	0.33	0.277		
D	5	.15 BS0	2		
D1	4.85	4.95	4.90		
D2	-	-	3.98		
E	6.15 BSC				
E1	5.75	5.85	5.80		
E2	3.56	3.725	3.66		
е	1	.27BSC	)		
k	-	-	1.27		
L	0.51	0.71	0.61		
La	0.51	0.675	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type K)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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